


APPLICATION DATA SHEET

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Title of Invention	[GATE STRUCTURE FORMING METHOD OF FIELD EFFECT TRANSISTOR]	
Application Type : regular, utility Attorney Docket Number : 11248-US-PA		
Correspondence address: Customer Number: 31561 		
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as our attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.